

Dual N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^d	Q _g (Typ.)
100	0.017 at V _{GS} = 10 V	30	16 nC

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

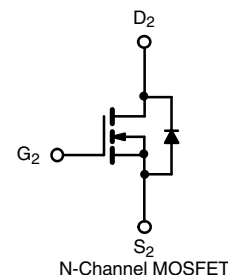
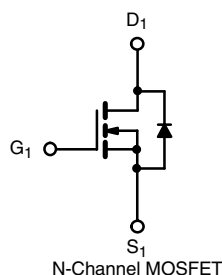
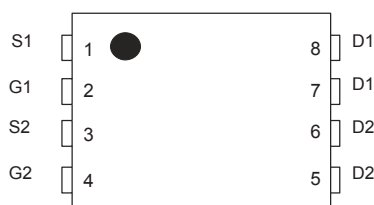


RoHS
COMPLIANT

APPLICATIONS

- Synchronous Buck Shoot-Through Resistant
- Optimized for Primary Side Switch

Top View



ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	± 20	
Continuous Drain Current (T _J = 150 °C) ^a	I _D	T _A = 25 °C	30
		T _A = 70 °C	19
Pulsed Drain Current	I _{DM}	120	A
Continuous Source Current (Diode Conduction) ^a	I _S	30	
Single Avalanche Current	L = 0.1 mH I _{AS}	27	
Single Avalanche Energy	E _{AS}	68	mJ
Maximum Power Dissipation ^a	P _D	T _A = 25 °C	49
		T _A = 70 °C	33
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C
Soldering Recommendations (Peak Temperature)		260	

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	R _{thJA}	t ≤ 10 s	56	85
		Steady State	80	110
Maximum Junction-to-Case (Drain)	R _{thJC}	2.1	3.0	°C/W

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

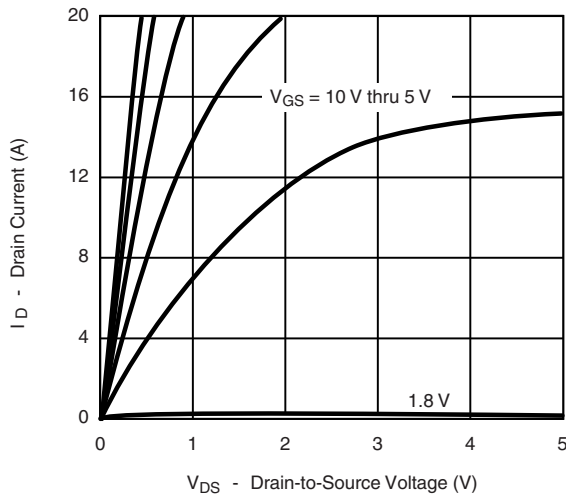
SPECIFICATIONS $T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1		3	V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}$			1	μA
		$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			5	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq 5\text{ V}, V_{GS} = 10\text{ V}$	30			A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 15\text{ A}$		0.017	0.022	Ω
		$V_{GS} = 4.5\text{ V}, I_D = 10\text{ A}$		0.020	0.028	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15\text{ V}, I_D = 10\text{ A}$		18		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.9\text{ A}, V_{GS} = 0\text{ V}$		0.8	1.2	V
Dynamic^b						
Input Capacitance	C_{iss}	$V_{DS} = 50\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		1345		μF
Output Capacitance	C_{oss}			306		
Reverse Transfer Capacitance	C_{rss}			13		
Total Gate Charge	Q_g	$V_{DS} = 50\text{ V}, V_{GS} = 10\text{ V}, I_D = 15\text{ A}$		16	24	nC
Gate-Source Charge	Q_{gs}			3.8		
Gate-Drain Charge	Q_{gd}			5.5		
Gate Resistance	R_g			2.2		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 50\text{ V}, R_L = 50\text{ }\Omega$ $I_D \cong 1\text{ A}, V_{GEN} = 10\text{ V}, R_g = 6\text{ }\Omega$		5		ns
Rise Time	t_r			3		
Turn-Off Delay Time	$t_{d(off)}$			20		
Fall Time	t_f			5		
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = 2.9\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		50		

Notes:

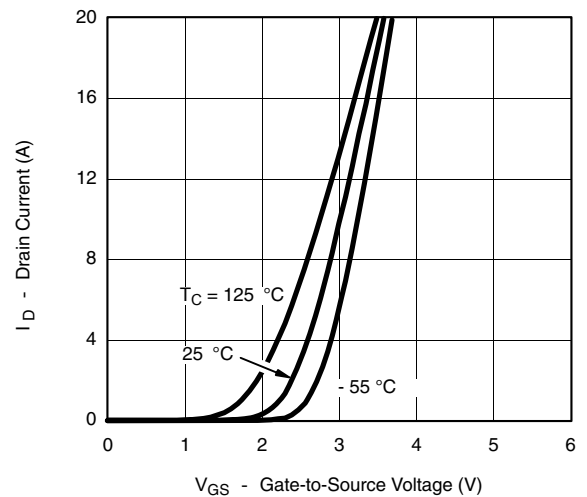
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

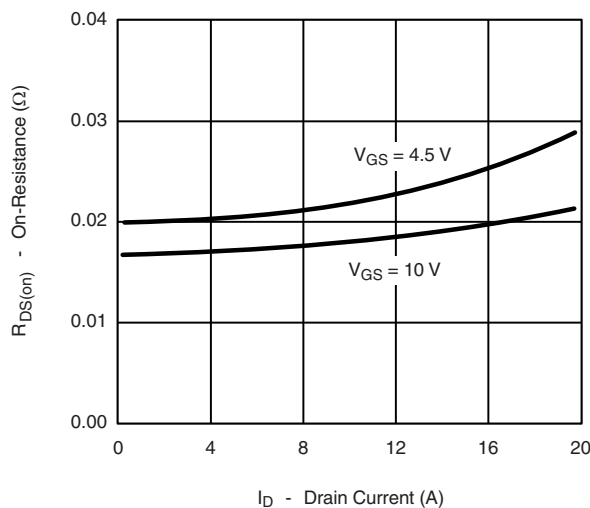
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



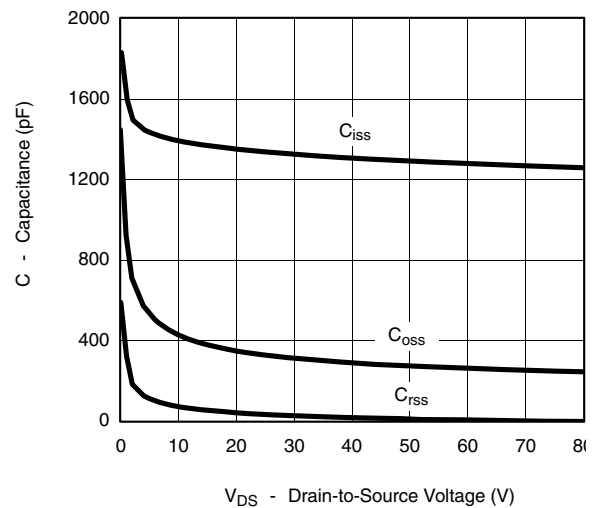
Output Characteristics



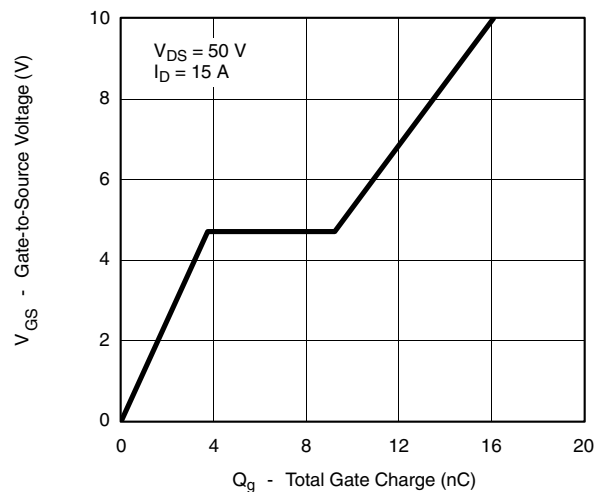
Transfer Characteristics



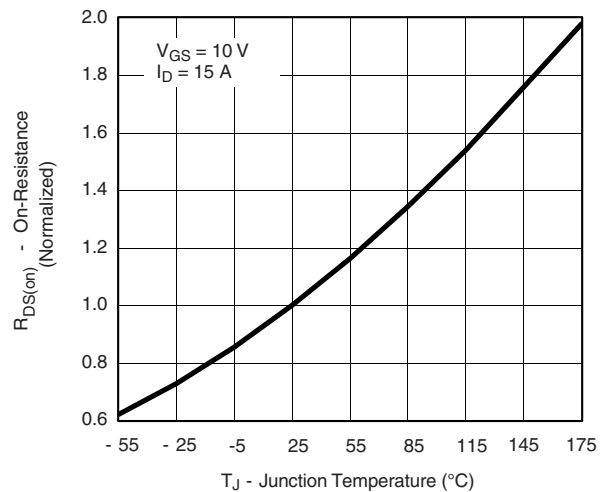
On-Resistance vs. Drain Current



Capacitance

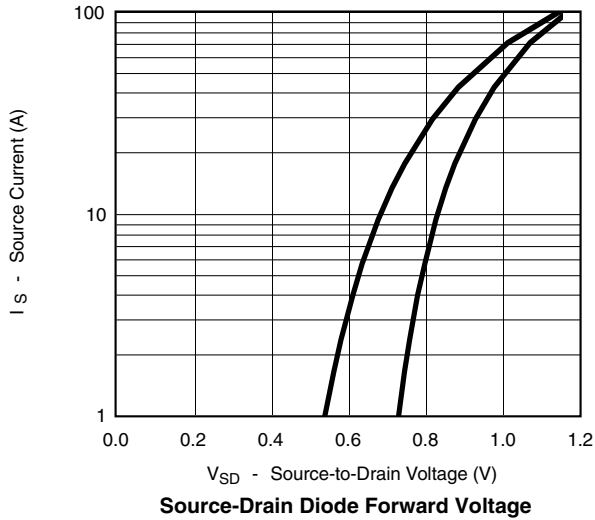


Gate Charge

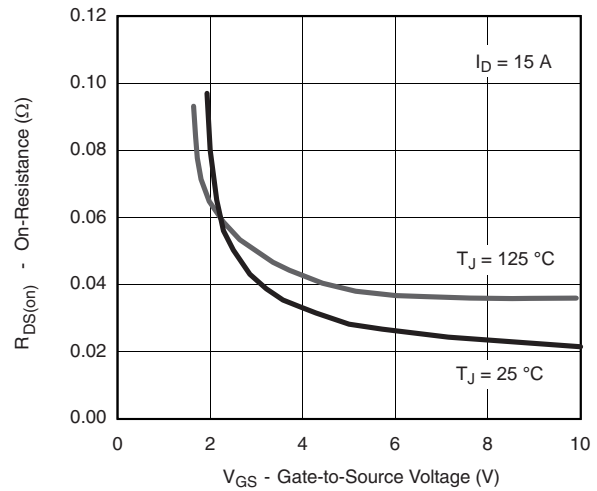


On-Resistance vs. Junction Temperature

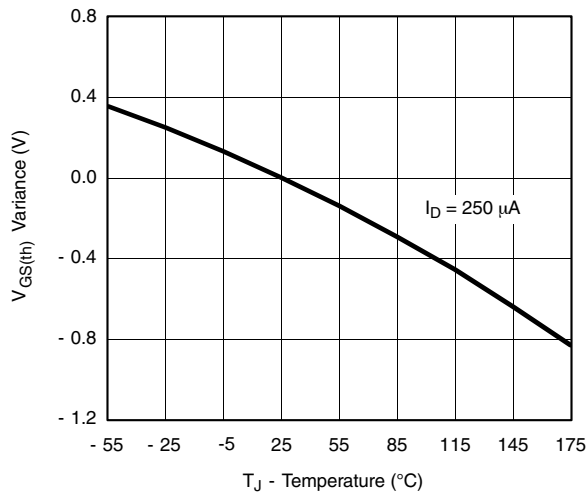
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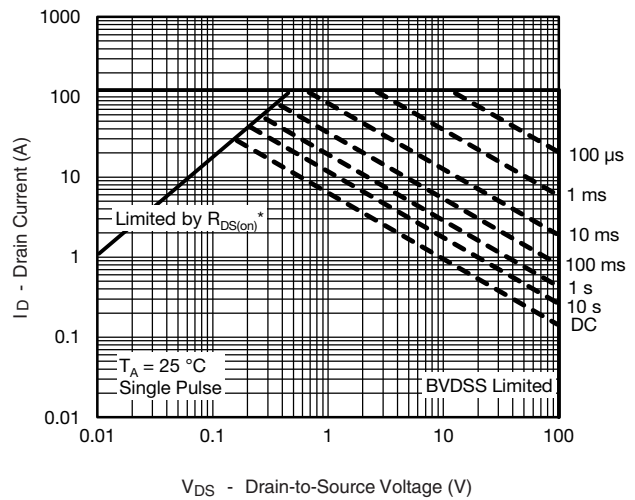
Source-Drain Diode Forward Voltage



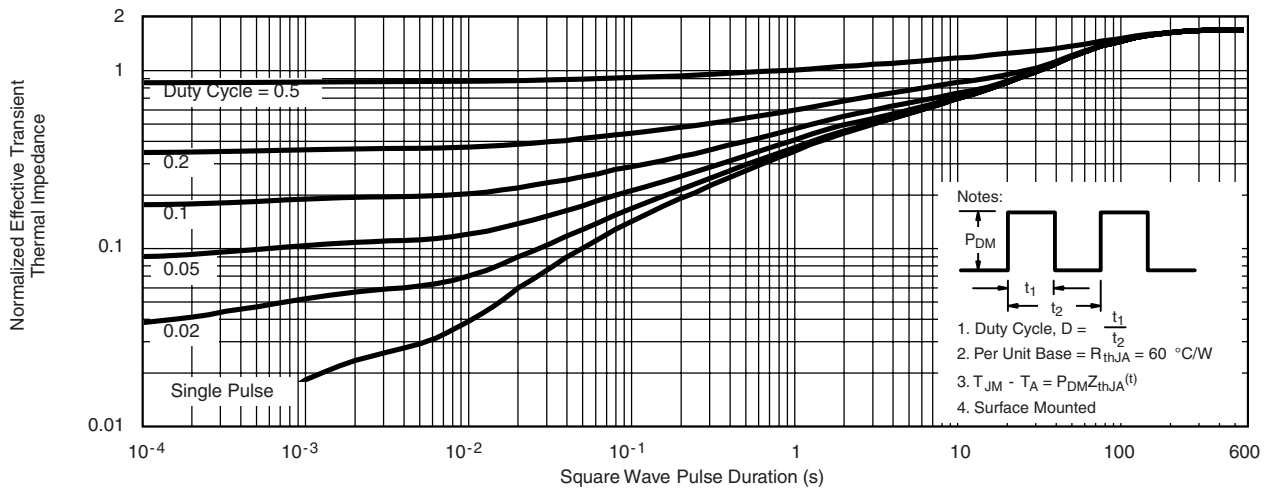
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



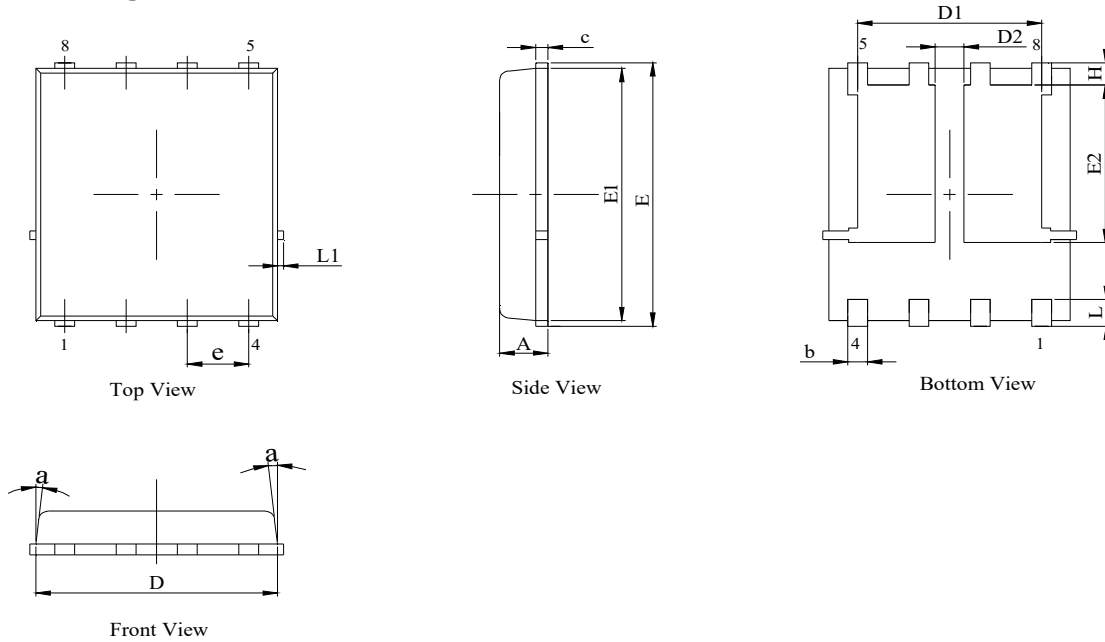
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient

PDFN5x6_Dual Package Information

Package Outline

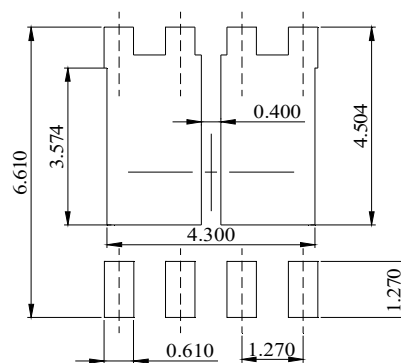


NOTES:

1. Dimension and tolerance per ASME Y14.5M, 1994.
2. All dimensions in millimeter (angle in degree).
3. Dimensions D and E1 do not include mold flash protrusions or gate burrs.

DIM.	MILLIMETER	
	MIN.	MAX.
A	0.90	1.10
b	0.33	0.51
c	0.23	0.33
D	4.80	5.40
D1	3.61	4.25
D2	0.50	0.70
E	5.90	6.25
E1	5.55	5.80
E2	3.35	3.78
e	1.27 BSC	
H	0.41	0.80
L	0.51	0.80
L1	-	0.15
a	0°	12°

Recommended Footprint



DIMENSIONS: MILLIMETERS

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